TOSHIBA Photocoupler IRED & Photo IC

# **TLP550**

Microprocessor System Interfaces
Digital Logic Ground Isolation
Line Receiver
Switching Power Supply Feedback Control
Transistor Inverter

TLP550 consists of a high-output infrared emitting diode and a one chip photo diode—transistor.

TLP550 has no base connection, and is suitable for application at noisy environmental condition.

This unit is 8-lead DIP package.

- Isolation voltage : 2500 Vrms (min)
- Propagation delay time (tpHL / tpLH):

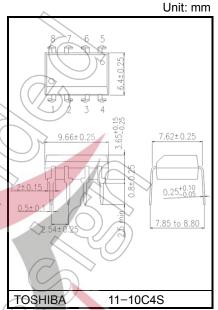
 $t_{pHL} = 0.5 \mu s$  (typ.),

 $t_{pLH} = 0.6 \mu s$  (typ.)

 $(R_L=1.9 \text{ k}\Omega)$ 

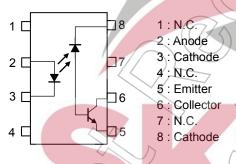
- TTL compatible
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A

File No.E67349

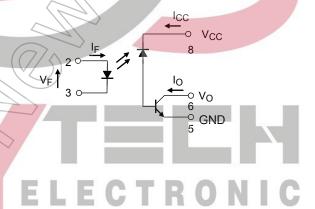


Weight: 0.54 g (typ.)

### Pin Configuration (top view)



### **Schematic**



Start of commercial production 1981-09

#### **Current Transfer Ratio**

Classification		sfer Ratio (%) /I <sub>F</sub> )	Marking of Classification
	Min	Max	, and the second
(None)	10	_	Blank, O, Y
Rank O	19	_	0
Rank Y	35	_	Υ

### Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Forward current	(Note 1)	(F	25	mA
Pulse forward current	(Note 2)	IEP I	50	mA
Peak transient forward current	(Note 3)	IFPT .	1	A
Reverse voltage		VR	5	>
Diode power dissipation	(Note 4)	PD	45	mW
Output current		10	8	mΑ
Peak output current		IOP	16	mA
Supply voltage	4()	Vcc	-0.5 to 15	V
Output voltage		Vo	-0.5 to 15	٧
Output power dissipation	(Note 5)	Po	)) 100	mW
rating temperature range	Topr	-55 to 100	°C	
age temperature range	T <sub>stg</sub>	−55 to 125	°C	
Lead solder temperature (10 s)			260	°C
ation voltage (AC, 60 s, R.H. ≤ 60 %)	BVS	2500	Vrms	
	Forward current  Pulse forward current  Peak transient forward current  Reverse voltage  Diode power dissipation  Output current  Peak output current  Supply voltage  Output voltage  Output power dissipation  rating temperature range  age temperature range	Forward current (Note 1)  Pulse forward current (Note 2)  Peak transient forward current (Note 3)  Reverse voltage  Diode power dissipation (Note 4)  Output current  Peak output current  Supply voltage  Output voltage  Output power dissipation (Note 5)  rating temperature range  age temperature range  d solder temperature (10 s)	Forward current  Pulse forward current  (Note 2)  Peak transient forward current  Reverse voltage  Diode power dissipation  Output current  Peak output current  Iop  Supply voltage  Output voltage  Output power dissipation  (Note 5)  Po  rating temperature range  d solder temperature (10 s)	Forward current  Pulse forward current  (Note 1)  Peak transient forward current  (Note 2)  Peak transient forward current  (Note 3)  IFPT  1  Reverse voltage  VR  5  Diode power dissipation  (Note 4)  PD  45  Output current  IO  8  Peak output current  IoP  16  Supply voltage  Vcc  0.5 to 15  Output voltage  Vo  -0.5 to 15  Output power dissipation  (Note 5)  Po  100  rating temperature range  age temperature range  d solder temperature (10 s)  Tsol  260

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Derate 0.8mA above 70 °C.

(Note 2) 50 % duty cycle, 1 ms pulse width. Derate 1.6 mA / °C above 70 °C.

(Note 3) Pulse width 1 µs, 300 pps.

(Note 4) Derate 0.9 mW / °C above 70 °C

(Note 5) Derate 2 mW / °C above 70 °C.

ELECTRONIC

(Note 6) Device considered two-terminal device: Pins 1, 2, 3 and 4 shorted together and pin 5, 6, 7 and 8 shorted together.

#### **Electrical Characteristics (Ta = 25°C)**

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I <sub>F</sub> = 16 mA	1.45	1.65	1.85	V
	Forward voltage temperature coefficient	ΔV <sub>F</sub> / ΔTa	IF = 16 mA	_	-2		mV / °C
=	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	7	-	10	μА
	Capacitance between terminal	Ст	V <sub>F</sub> = 0 V, f = 1 MHz		60	_	pF
		IOH (1)	IF = 0 mA, V <sub>CC</sub> = V <sub>O</sub> = 5.5 V		3	500	nA
	High level output current	IOH (2)	I <sub>F</sub> = 0 mA, V <sub>CC</sub> = V <sub>O</sub> = 15 V	/ <del>\</del>	-	5	
Detector	and the second second	Іон	I <sub>F</sub> = 0 mA, V <sub>CC</sub> = 15 V V <sub>O</sub> = 15 V, Ta = 70 °C	2	_	50	μΑ
De	High level supply voltage	Іссн	IF = 0 mA, VCC = 15 V	-	0.01	1	μА
	Supply voltage	Vcc	ICC = 0.01 mA	15		_	V
	Output voltage	Vo	I <sub>O</sub> = 0.5 mA	15	9/	$\rightarrow$	V

### Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
	IO/IF	IF = 16 mA,	10	40	_	
		VCC = 4.5V, Rank O	19	40	_	
Current transfer ratio		Vo = 0.4 V Rank Y	35	50	_	%
Current transfer ratio		I <sub>F</sub> = 16 mA, V <sub>CC</sub> = 4.5 V,	5	_	-	70
		V <sub>O</sub> = 0.4 V, Ta = 0 to 70°C Rank O, Y	15	_		
Low level output voltage	Vol	I <sub>F</sub> = 16 mA, V <sub>CC</sub> = 4.5 V, I <sub>O</sub> = 1.1 mA (Rank O: I <sub>O</sub> = 2.4 mA)	_	-	0.4	V

## Isolation Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input-output)	(Note 7)	Cs	Vs = 0 V, f = 1 MHz	-	0.8		pF
Resistance (input-output)	(Note 7)	Rs	R.H. ≤ 60 %, V <sub>S</sub> = 1 kV <sub>DC</sub>	5×10 <sup>10</sup>	10 <sup>14</sup>	7-	Ω
Isolation voltage	(Note 7)	BVs	AC, 60 s	2500			V <sub>rms</sub>

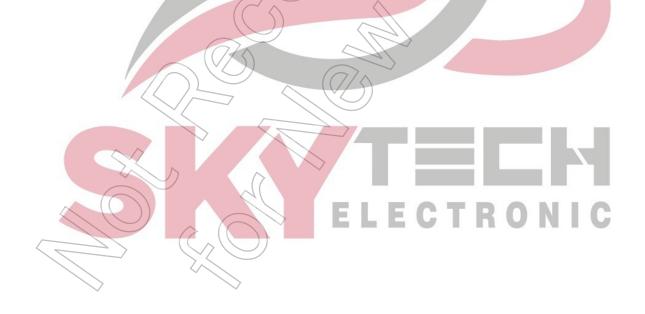
(Note 7) Device considered two-terminal device: Pins 1, 2, 3 and 4 shorted together and pin 5, 6, 7 and 8 shorted together.

### Switching Characteristics (Ta = 25°C, Vcc = 5V)

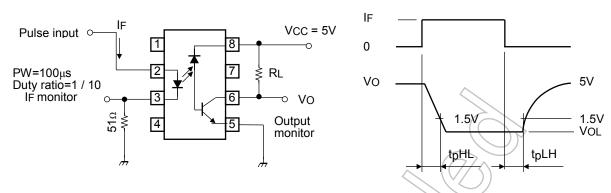
Characteristic	Symbol	Test Circuit.	Test Condition	Min	Тур.	Max	Unit
Propagation delay time			$I_F = 0 \rightarrow 16 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 4.1 \text{ k}\Omega$	_	0.3	0.8	
$(H \rightarrow L)$	t <sub>pHL</sub>		Rank O: R <sub>L</sub> = 1.9 kΩ		0.5	0.8	μS
Propagation delay time (L→ H)	tpLH	1	$I_F = 16 \rightarrow 0$ mA, $V_{CC} = 5$ V, $R_L = 4.1$ k $\Omega$		) 1	2	
			Rank O; R <sub>L</sub> = 1.9 kΩ	<del>/</del>	0.6	1.2	μS
Common mode transient immunity at high output level	Смн		$I_F$ = 0 mA, $V_{CM}$ = 200 $V_{p-p}$ $R_L$ = 4.1 kΩ (rank O: $R_L$ = 1.9 kΩ) (Note 8)	_	1500	_	V /μs
Common mode transient immunity at low output level	CML	2	$I_F$ = 16 mA, $V_{CM}$ = 200 $V_{p-p}$ $R_L$ = 4.1 kΩ (rank O: $R_L$ = 1.9 kΩ) (Note 8)	-50	-1500	<i>&gt;&gt;</i>	V /μs

(Note 8) CML is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state (Vo < 0.8 V).

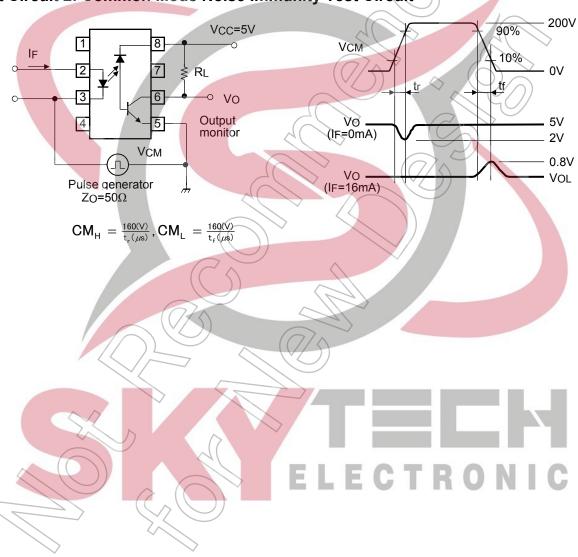
CM<sub>H</sub> is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic high state (V<sub>O</sub> > 2.0 V).

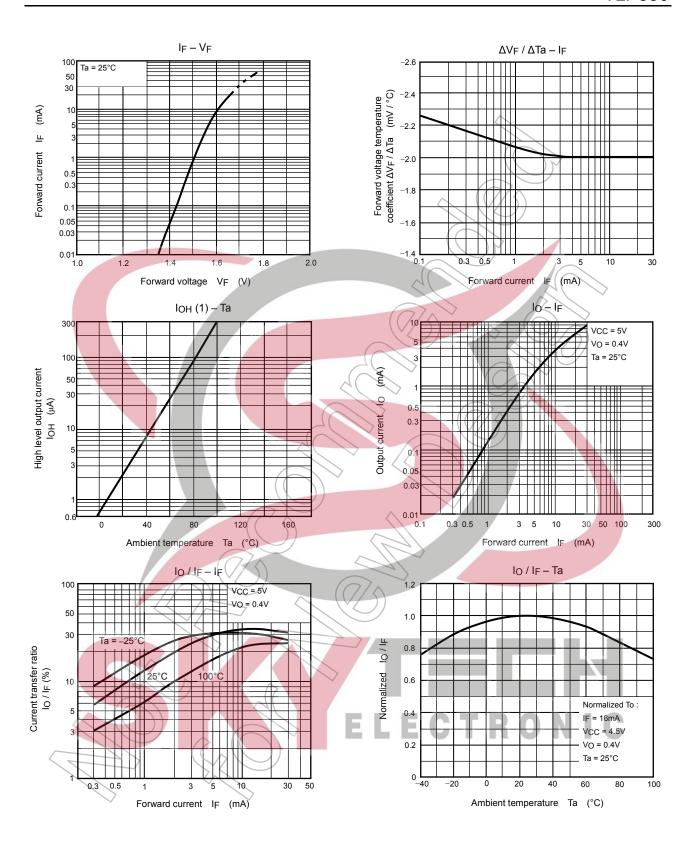


#### **Test Circuit 1: Switching Time Test Circuit**

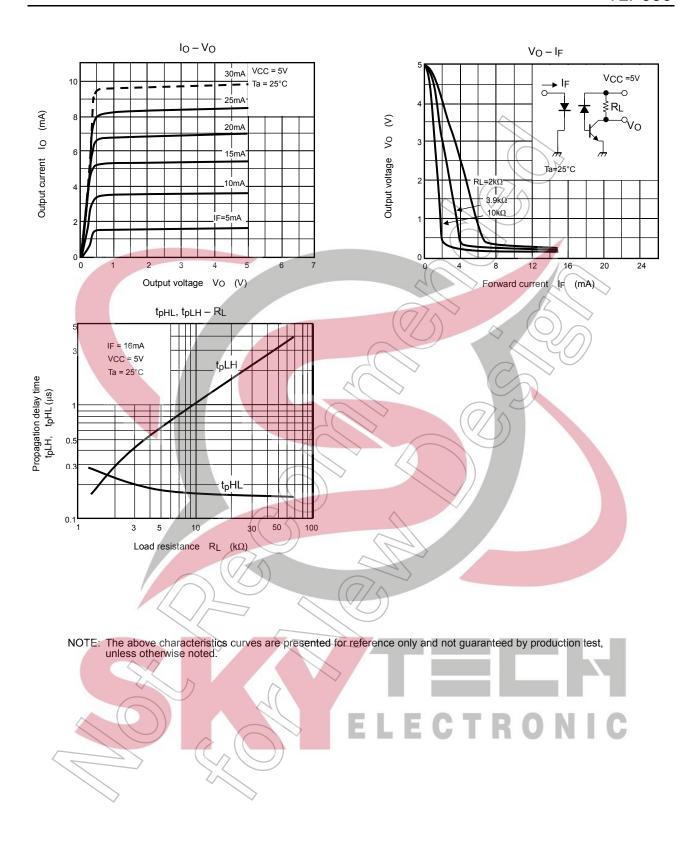


### Test Circuit 2: Common Mode Noise Immunity Test Circuit





NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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